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XO5070x-C
2.5/3.3V LVPECL Output
Crystal Oscillator

Features

- 2.25 to 3.63V operating supply voltage range
- Operating frequency range (varies with version)
 - 10MHz to 320MHz fundamental oscillation
 - 60MHz to 290MHz 3rd overtone oscillation
- -40 to 105°C operating temperature range
- Differential LVPECL output
- 50Ω output load (terminated to VDD-2V)
- Standby function: Output are high impedance when OE is LOW (oscillator stops)
- Power-saving pull-up resistor built-in (pin OE)
- CMOS process
- Die form and wafer form

Applications

- Used for crystal oscillator
- Used for 7050/5032/3225/2520 Package

Description

The XO5070-C series are 2.5V/3.3V operation, differential LVPECL output oscillator ICs. They support 10MHz to 320MHz fundamental and 60MHz to 290MHz 3rd overtone oscillator. The devices are fabricated using a proprietary CMOS process, enabling a high-frequency oscillator circuit and differential LVPECL output buffer to be incorporated on a single chip. The XO5070-C series can be used to construct high-frequency LVPECL output oscillators.

Ordering Information

| Part no. | Package type |
|---------------|--------------|
| XO5070x-yDE-C | Die form |
| XO5070x-yWF-C | Wafer form |

Note:

- 1."x" shows the different function. See below table.
- 2.“-y” shows the die thickness.” “-3” Stand for thickness 130+/-15um
- 3.“DE” stands for chip form, “WF” stands for Wafer form

Series Configuration

| Version | f _{output} | Oscillation | Frequency Range ^{*1} |
|-----------|---------------------|--------------------------|-------------------------------|
| XO5070A-C | F0 | Fundamental | 10~70MHz |
| XO5070B-C | F0 | | 60~100MHz |
| XO5070C-C | F0 | | 100~160MHz |
| XO5070D-C | F0 | | 200~260MHz |
| XO5070E-C | F0 | | 260MHz~320MHz |
| XO5070G-C | f0 | 3 rd overtone | 60MHz to 90MHz |
| XO5070H-C | f0 | | 70MHz to 120MHz |
| XO5070L-C | f0 | | 120MHz to 180MHz |
| XO5070N-C | f0 | | 180MHz to 290MHz |

Note: * 1. The recommended operating frequency is a yardstick value derived from the crystal used for RSM characteristics authentication. However, the oscillator frequency band is not guaranteed. Specifically, the characteristics can vary greatly due to crystal characteristics and mounting conditions, so the oscillation characteristics of components must be carefully evaluated.

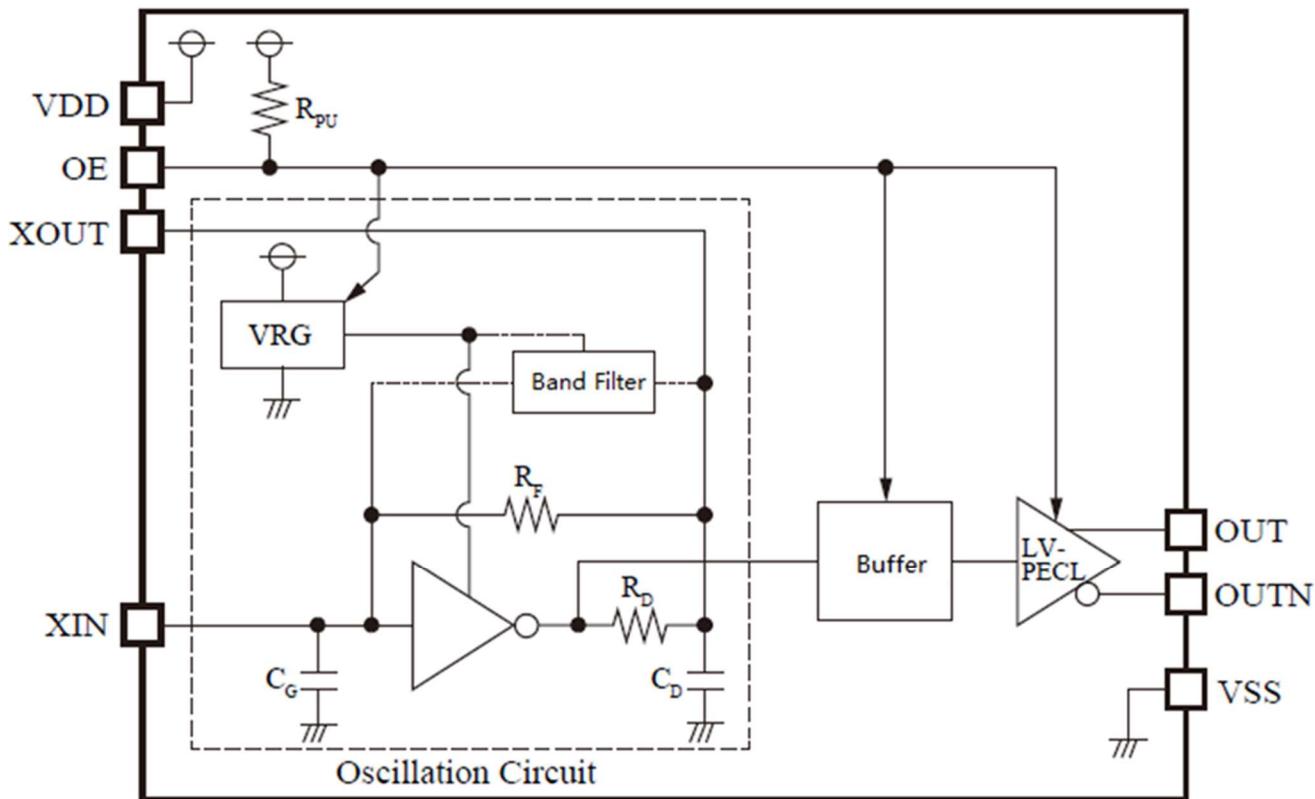


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Block Diagram



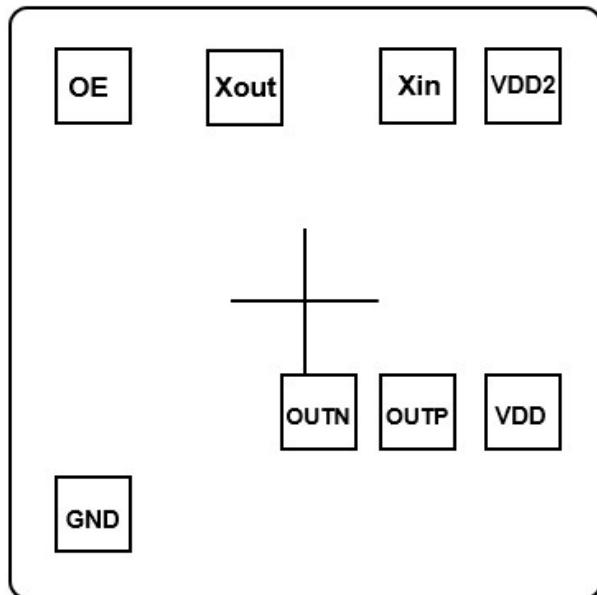


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Pad Configuration



Pad Coordinate File

| Pad Name | X Coordinate | Y Coordinate | Pad Name | X Coordinate | Y Coordinate |
|----------|--------------|--------------|----------|--------------|--------------|
| VDD2 | 253.995 | 226.5 | OE | -237.27 | 226.5 |
| XIN | 132.125 | 226.5 | OUTN | 6.125 | -130.165 |
| XOUT | -82.095 | 226.5 | OUTP | 132.125 | -130.165 |
| GND(VSS) | -225.345 | -210.825 | VDD | 253.995 | -130.165 |

Note: Substrate is connected to GND or floating.

Die Size: 640um*580um (Not Including scribe line size 65um*65um.)

Pad Size: 80um*80um

Pad Description

| Sym. | Type | Description |
|--------------|------|---|
| VDD VDD2 | P | Supply voltage. |
| XIN | I | Oscillator input pin. |
| XOUT | O | Oscillator output pin. |
| GND (VSS) | P | Ground (-). |
| OE | I | Output enable pin. Output are high impedance when LOW (oscillator stopped). Power-saving pull-up resistor built-in. |
| OUTN | O | Output pin (complementary). |
| OUTP | O | Output pin (true). |



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Function Description

Standby Function

When OE goes LOW, the oscillator stops and the output pins (OUT, OUTN) become high impedance.

| OE | OUT ,OUTN | Oscillator |
|----------------|----------------|------------------|
| HIGH (or open) | f0 | Normal operation |
| LOW | High impedance | Stopped |

Power-saving Pull-up Resistor

The OE pin pull-up resistance changes in response to the input level (HIGH or LOW). When OE is tied LOW (standby state), the pull-up resistance becomes large, reducing the current consumed by the resistance. When OE is open circuit, the pull-up resistance becomes small, decreasing the susceptibility to the effects of external noise.

Absolute Maximum Ratings

| Symbol | Parameter | MIN | TYP | MAX | Unit |
|--------------------|----------------------|------|-----|----------------------|------|
| T _{store} | Storage Temperature | -65 | - | +150 | °C |
| V _{DD} | Supply Voltage Range | -0.5 | - | 5.0 | V |
| V _{IN} | Input Voltage Range | -0.5 | - | V _{DD} +0.5 | V |
| V _{OUT} | Output Voltage Range | -0.5 | - | V _{DD} +0.5 | V |

Note:

- Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

| Sym. | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------|-----------------------|-----------------------------------|------|-----|-----------------|------|
| V _{DD} | Supply voltage | - | 2.25 | - | 3.63 | V |
| V _{IN} | Input voltage | - | GND | - | V _{DD} | V |
| T _A | Operating temperature | XO5070x-C | -40 | +25 | +105 | °C |
| R _L | Output load | Terminated to V _{DD} -2V | 49.5 | 50 | 50.5 | Ω |
| F _{OUT} | Output frequency | fundamental | 10 | - | 320 | MHz |
| | | 3 rd overtone | 60 | | 290 | MHz |



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DC Electrical Characteristics

3.3V operation ($V_{DD} = 2.97$ to $3.63V$, $T_A = -40$ to $105^\circ C$, GND = 0V, unless otherwise noted.)

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|---------------------------|--|-------------|-----|-------------|---------|
| I_{EE1} | Current consumption1 | Measurement cct.1, OE=open | - | 40 | 60 | mA |
| I_{EE2} | Current consumption2 | Measurement cct.1, OE=LOW | - | - | 30 | μA |
| V_{OH} | HIGH-level output voltage | Measurement cct.2, $V_{DD}=3.3V$, OE=open, OUT, OUTN pins | 2.2 | 2.4 | 2.6 | V |
| V_{OL} | LOW-level output voltage | | 1.4 | 1.6 | 1.8 | V |
| I_Z | Output leakage current | Measurement cct.3, OE=LOW, OUT, OUTN pins | - | - | 10 | μA |
| V_{IH} | HIGH-level input voltage | Measurement cct.1, OE pin | $0.7V_{DD}$ | - | - | V |
| V_{IL} | LOW-level input voltage | Measurement cct.1, OE pin | - | - | $0.3V_{DD}$ | V |
| I_{IL1} | LOW-level input current1 | Measurement cct.1, $V_{IL}=0V$, OE pin | 0 | - | -20 | μA |
| I_{IL2} | LOW-level input current2 | Measurement cct.1, $V_{IL}=0.7V_{DD}$, OE pin | -1 | - | -150 | μA |

2.5V operation ($V_{DD} = 2.25$ to $2.75V$, $T_A = -40$ to $105^\circ C$, GND = 0V, unless otherwise noted.)

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|---------------------------|--|-------------|-----|-------------|---------|
| I_{EE1} | Current consumption1 | Measurement cct.1, OE=open | - | 38 | 60 | mA |
| I_{EE2} | Current consumption2 | Measurement cct.1, OE=LOW | - | - | 30 | μA |
| V_{OH} | HIGH-level output voltage | Measurement cct.2, $V_{DD}=2.5V$, OE=open, OUT, OUTN pins | 1.4 | 1.6 | 1.8 | V |
| V_{OL} | LOW-level output voltage | | 0.6 | 0.8 | 1.0 | V |
| I_Z | Output leakage current | Measurement cct.3, OE=LOW, OUT, OUTN pins | - | - | 10 | μA |
| V_{IH} | HIGH-level input voltage | Measurement cct.1, OE pins | $0.7V_{DD}$ | - | - | V |
| V_{IL} | LOW-level input voltage | Measurement cct.1, OE pins | - | - | $0.3V_{DD}$ | V |
| I_{IL1} | LOW-level input current1 | Measurement cct.1, $V_{IL}=0V$, OE pins | 0 | - | -20 | μA |
| I_{IL2} | LOW-level input current2 | Measurement cct.1, $V_{IL}=0.7V_{DD}$, OE pins | -1 | - | -150 | μA |



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AC Electrical Characteristics

3.3V operation ($V_{DD} = 2.97$ to $3.63V$, $T_A = -40$ to $105^\circ C$, GND = 0V, unless otherwise noted.)

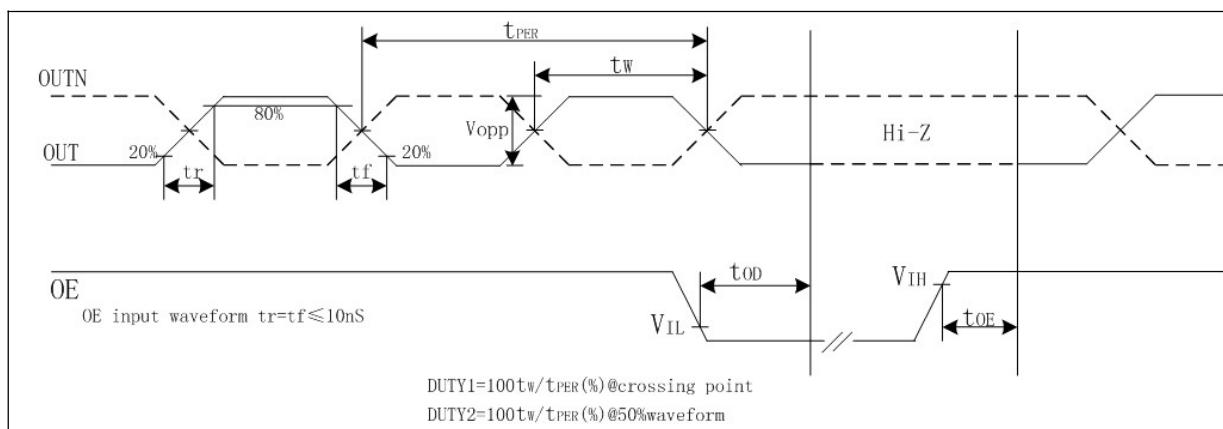
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------------|----------------------------------|--|-----|-----|-----|------|
| Duty1 | Output duty cycle1 | Measurement cct.4, measured at output crossing point, $T_A=25^\circ C$, $V_{DD}=3.3V$ | 45 | - | 55 | % |
| Duty2 | Output duty cycle2 | Measurement cct.4, measured at 50% output swing, $T_A=25^\circ C$, $V_{DD}=3.3V$ | 45 | - | 55 | % |
| Vopp | Output swing | Measurement cct.4, Peak to Peak of single output wave | 0.6 | 0.8 | - | V |
| tr | Output rise time | Measurement cct.4, 20 to 80% output swing | - | 0.2 | 0.4 | ns |
| tf | Output fall time | Measurement cct.4, 80 to 20% output swing | - | 0.2 | 0.4 | ns |
| t _{OE} | Output enable time ^{*1} | Measurement cct.5, $T_A=25^\circ C$ | - | - | 2 | ms |
| t _{OD} | Output disable time | Measurement cct.5, $T_A=25^\circ C$ | - | - | 200 | ns |

2.5V operation ($V_{DD} = 2.25$ to $2.75V$, $T_A = -40$ to $105^\circ C$, GND = 0V, unless otherwise noted.)

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------------|----------------------------------|--|-----|------|-----|------|
| Duty1 | Output duty cycle1 | Measurement cct.4, measured at output crossing point, $T_A=25^\circ C$, $V_{DD}=2.5V$ | 45 | - | 55 | % |
| Duty2 | Output duty cycle2 | Measurement cct.4, measured at 50% output swing, $T_A=25^\circ C$, $V_{DD}=2.5V$ | 45 | - | 55 | % |
| Vopp | Output swing | Measurement cct.4, Peak to Peak of single output wave | 0.5 | 0.7 | - | V |
| tr | Output rise time | Measurement cct.4, 20 to 80% output swing | - | 0.25 | 0.5 | ns |
| tf | Output fall time | Measurement cct.4, 80 to 20% output swing | - | 0.25 | 0.5 | ns |
| t _{OE} | Output enable time ^{*1} | Measurement cct.5, $T_A=25^\circ C$ | - | - | 2 | ms |
| t _{OD} | Output disable time | Measurement cct.5, $T_A=25^\circ C$ | - | - | 200 | ns |

Note: *1: The built-in oscillator stop function does not operate with normal output immediately when OE goes HIGH. Instead, normal output occurs after the oscillator startup time has elapsed.

Timing chart





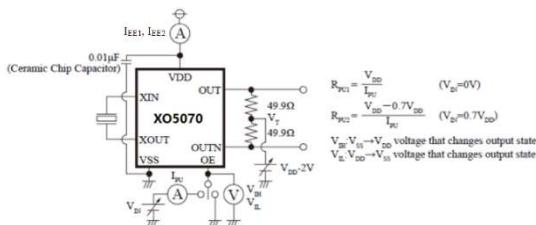
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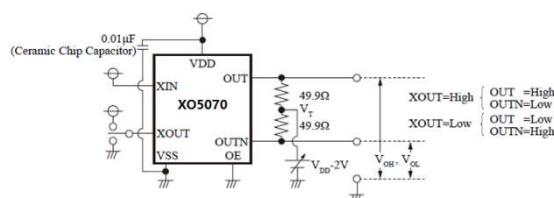
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Measurement Circuit

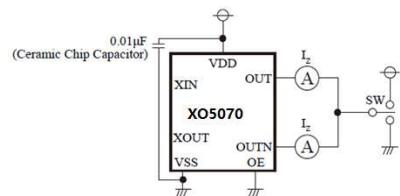
Measurement Circuit 1: I_{EE1}, I_{EE2}, V_{IH}, V_{IL}, R_{PUI1}, R_{PUI2}



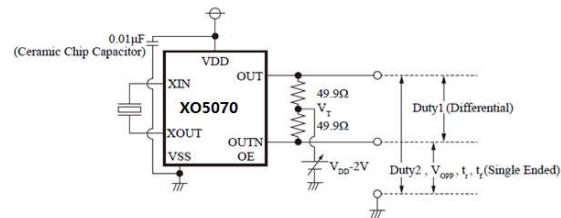
Measurement Circuit 2: V_{OL}, V_{OH}



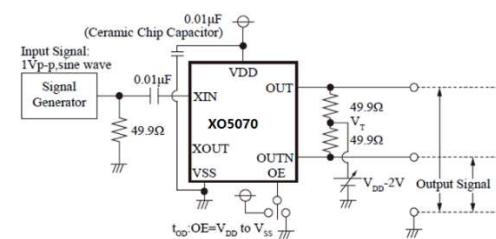
Measurement Circuit 3: I_Z



Measurement Circuit 4: Duty1, Duty2, V_{OOPP}, t_r, t_f



Measurement Circuit 5: t_{OD}

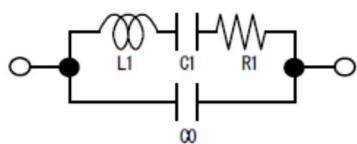


Reference Data

The following characteristics are measured using the crystal below. Note that the characteristics will vary with the crystal used.

| Parameter | f ₀ =125.00MHz | f ₀ =156.25MHz |
|-----------|---------------------------|---------------------------|
| C0(pF) | 1.8 | 1.2 |
| R1(Ω) | 35 | 60 |

Crystal parameters





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History Log:

| Revision | Description | Date |
|----------|---------------------|-----------|
| V0.9 | Preliminary release | 2025/3/26 |



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